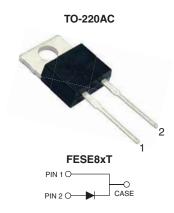
RoHS



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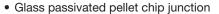
Ultrafast Plastic Rectifier



PRIMARY CHARACTERISTICS								
I _{F(AV)}	8.0 A							
V_{RRM}	50 V to 600 V							
I _{FSM}	125 A							
t _{rr}	35 ns, 50 ns							
V _F	0.95 V, 1.30 V, 1.50 V							
T _J max.	150 °C							
Package	TO-220AC							
Diode variations	Single die							

FEATURES

Power pack





· Low switching losses, high efficiency

Low leakage current

· High forward surge capability

- Solder dip 275 °C max., 10 s per JESD 22-B106
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

MECHANICAL DATA

Case: TO-220AC

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)										
PARAMETER	SYMBOL	FESE8AT	FESE8BT	FESE8CT	FESE8DT	FESE8FT	FESE8GT	FESE8HT	FESE8JT	UNI
Max. repetitive peak reverse voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Max. RMS voltage	V _{RMS}	35	70	105	140	210	280	350	420	V
Max. DC blocking voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Max. average forward rectified current at T _C = 100 °C	I _{F(AV)}		8.0							А
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}		125							А
Operating storage and temperature range	T _J , T _{STG}		-55 to +150							°C



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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)														
PARAMETER	TEST CONDITIONS		SYMBOL	FESE8AT	FESE8BT	FESE8CT	FESE8DT	FESE8FT	FESE8GT	FESE8HT	FESE8JT	UNIT		
Max. instantaneous forward voltage (1)	8.0 A		V _F		0.95 1.3 1.4				.5	V				
Max. DC reverse current at rated DC		T _C = 25 °C		10										
blocking voltage		T _C = 100 °C	I _R	500						μA				
Max. reverse recovery time	I _F = 0. I _{rr} = 0.	5 A, I _R = 1.0 .25 A	t _{rr}	35 50						35 50				ns
Typical junction capacitance	4.0 V,	1 MHz	CJ	85 50					pF					

Note

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)										
PARAMETER	SYMBOL	FESE8AT	ESE8AT FESE8BT FESE8CT FESE8DT FESE8FT FESE8GT FESE8HT FESE8JT U							UNIT
Typical thermal resistance from junction to case	$R_{\theta JC}$	2.2					°C/W			

ORDERING INFORMATION (Example)										
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE					
TO-220AC	FESE8JT-E3/45	1.80	45	50/tube	Tube					

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

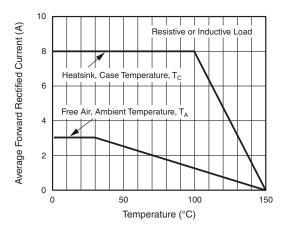


Fig. 1 - Max. Forward Current Derating Curve

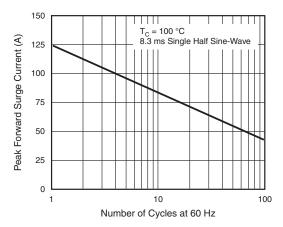


Fig. 2 - Max. Non-Repetitive Peak Forward Surge Current

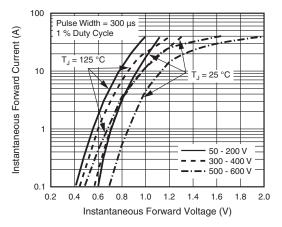


Fig. 3 - Typical Instantaneous Forward Characteristics

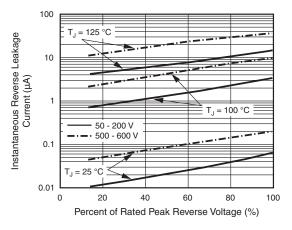


Fig. 4 - Typical Reverse Leakage Characteristics

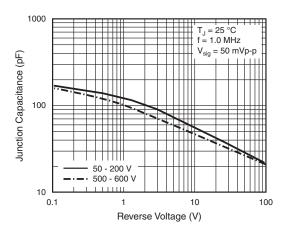
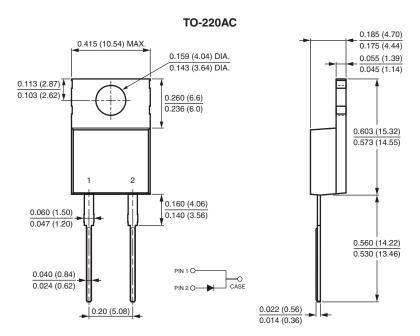


Fig. 5 - Typical Junction Capacitance



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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